

# 2SD869

SILICON NPN TRIPLE DIFFUSED MESA TYPE

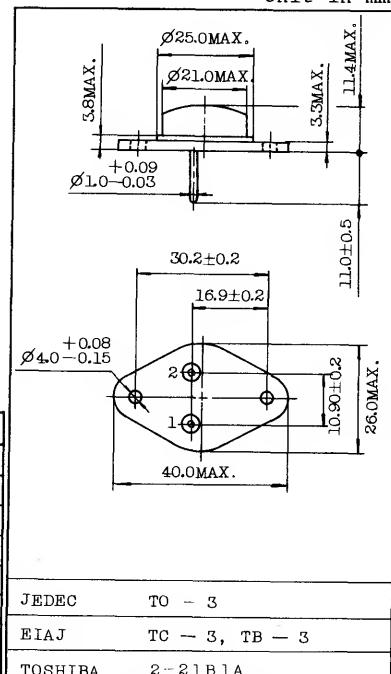
COLOR TV HORIZONTAL OUTPUT APPLICATIONS.

FEATURES:

- High Voltage :  $V_{CBO}=1500V$
- Low Saturation Voltage :  $V_{CE(sat)}=5V$  (Typ.) ( $I_C=3A$ ,  $I_B=0.8A$ )
- High Speed :  $t_f=1.0\mu s$  (Max.) ( $I_{CP}=3A$ ,  $I_{B1(end)}=0.8A$ )
- Built-in Damper Type.
- Glass Passivated Collector-Base Junction.

INDUSTRIAL APPLICATIONS

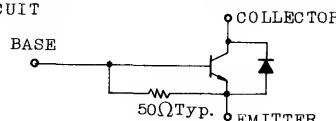
Unit in mm



JEDEC TO - 3  
EIAJ TC - 3, TB - 3  
TOSHIBA 2-21B1A

Mounting Kit No. AC42C  
Weight : 17g

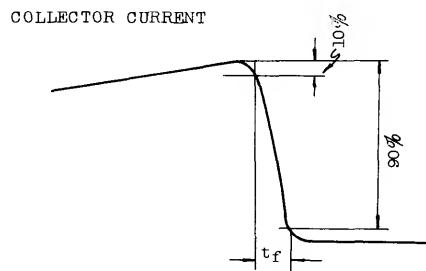
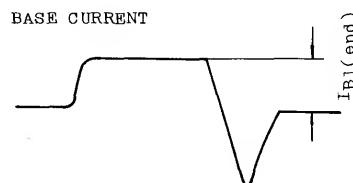
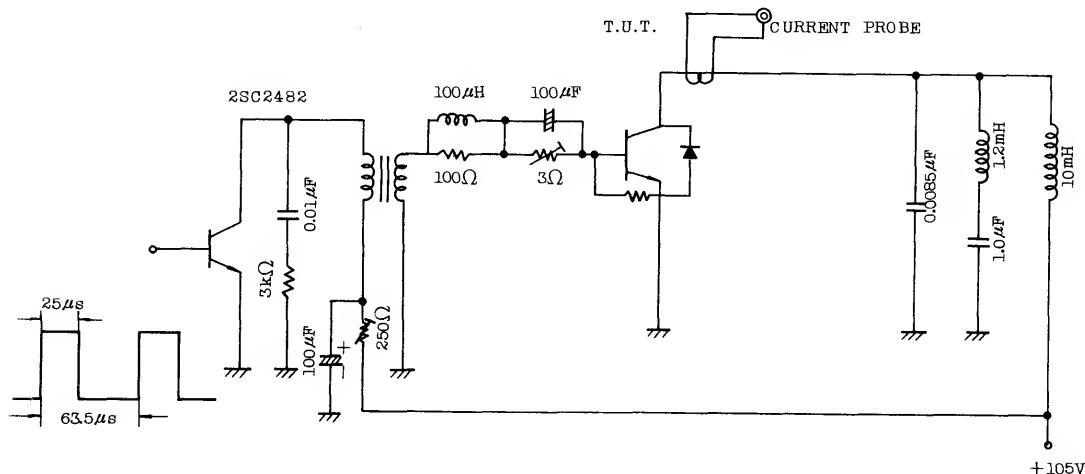
EQUIVALENT CIRCUIT



ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=500V$ , $I_E=0$	-	-	10	$\mu A$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=200mA$ , $I_C=0$	5	-	-	V
DC Current Gain	$h_{FE}$	$V_{CE}=5V$ , $I_C=0.5A$	8	12	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=3A$ , $I_B=0.8A$	-	5	8	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=3A$ , $I_B=0.8A$	-	-	1.5	V
Forward Voltage(Damper Diode)	$-V_F$	$I_F=3.5A$	-	1.6	2.0	V
Transition Frequency	$f_T$	$V_{CE}=10V$ , $I_C=0.1A$	-	3	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=10V$ , $I_E=0$ , $f=1MHz$	-	95	-	pF
Fall Time (Fig.)	$t_f$	$I_{CP}=3A$ , $I_{B1(end)}=0.8A$	-	0.5	1.0	$\mu s$

Fig.  $t_f$  TEST CIRCUIT



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